Product data sheet

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NXP Semiconductors



NXP Semiconductors Product specification

VHF variable capacitance diode

BB181

FEATURES

- Excellent linearity
- Ultra small plastic SMD package
- C28: 1 pF; ratio: 14.

APPLICATIONS

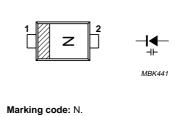
- · Electronic tuning in satellite tuners
- Tuneable coupling
- Voltage controlled oscillators (VCO).

DESCRIPTION

The BB181 is a variable capacitance diode, fabricated in planar technology and encapsulated in the SOD523 (SC-79) ultra small plastic SMD package.

PINNING

PIN	DESCRIPTION	
1	cathode	
2	anode	



Orientation of marking code as shown. Cathode side indicated by a bar.

Fig.1 Simplified outline (SOD523; SC-79) and symbol.

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V _R	continuous reverse voltage	_	30	V
I _F	continuous forward current	_	20	mA
T _{stg}	storage temperature	-55	+150	°C
Tj	operating junction temperature	-55	+150	°C

ELECTRICAL CHARACTERISTICS

 $T_i = 25$ °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I _R	reverse current	V _R = 30 V; see Fig.3	_	10	nA
		$V_R = 30 \text{ V}; T_j = 85 ^{\circ}\text{C}; \text{ see Fig.3}$	_	200	nA
r _s	diode series resistance	f = 470 MHz; note 1	_	3	Ω
C _d	diode capacitance	V _R = 0.5 V; f = 1 MHz; see Figs 2 and 4	8	17	pF
		V _R = 28 V; f = 1 MHz; see Figs 2 and 4	0.7	1.055	pF
$\frac{C_{d(0.5V)}}{C_{d(28V)}}$	capacitance ratio	f = 1 MHz	12	16	

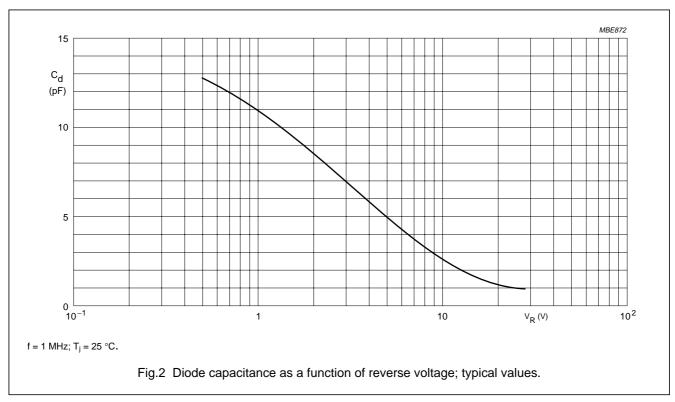
Note

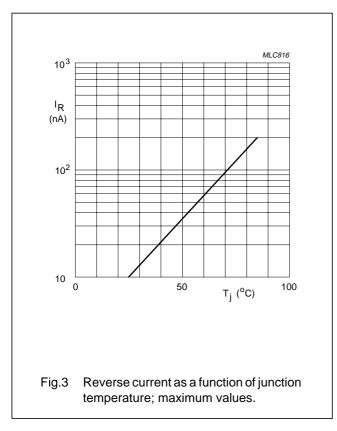
1. V_R is the value at which $C_d = 9$ pF.

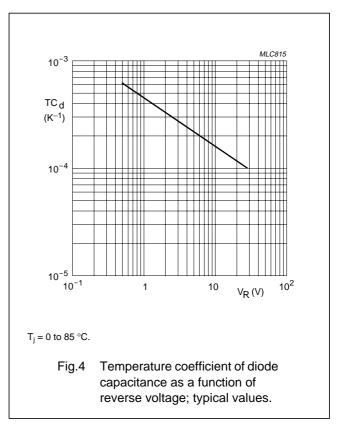
VHF variable capacitance diode

BB181

GRAPHICAL DATA







NXP Semiconductors Product specification

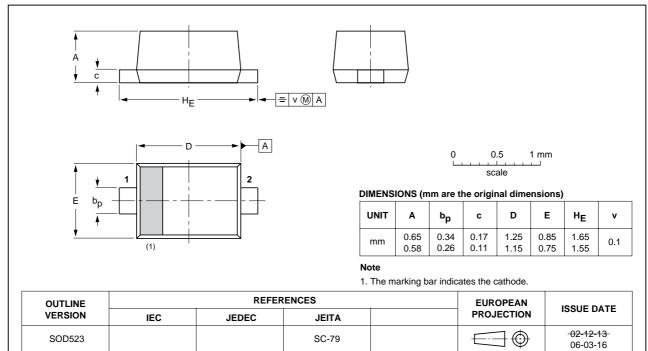
VHF variable capacitance diode

BB181

PACKAGE OUTLINE



SOD523



NXP Semiconductors

BB181

VHF variable capacitance diode

Legal information

Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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NXP Semiconductors BB181

VHF variable capacitance diode

Revision history

Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BB181_N_2	20080102	Product data sheet	-	BB181_1
Modifications: • Package outline drawing on page 4 changed				
BB181_1 (9397 750 04886)	19981126	Product specification	-	-

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